

- L62:162213 with 61
- L63:1722150 with 61
- L64:(218) 62 same 69
- L65:(27887617) (End of pdl) <20010830"
- L66:(1281) 64 and 65
- L67:(459911) graded
- L68:(415171) aluminum adj oxide "al sub.20 sub.3" al2o3 Al0 alumina)
- L69:(222) 67 near 6 68
- L70:(2) 69 near 6 2
- L71:(1912 near 6 67
- L72:(6023 23 near 6 68
- L73:(18180591) 2 35
- L74:(43) 72 same 73
- L75:(43) 74 same 68
- L76:(38) 75 not 40
- L77:(30) 76 and 65
- L78:(179128) aluminum adj oxide "al sub.20 sub.3" al2o3 Al0)
- L79:(56) 78 near 9 2
- L80:(8) 79 and 65
- L81:(7) 78 with (2 53)
- L82:(111) 78 same (2 53)
- L83:(31) 62 and 66
- L84:(888) srtio
- L85:(6) 78 near 9 84
- L86:(17) 78 with 64

Print Preview Close  
Search... Filter... Refresh... Help  
Search Query: 78

78 with 84

April 2005

Failed

U	I	Inventor	Document	Issue P	Title	Current	Patent	S	C	P	Image	Def
1		Denikou,Ale	US 200400	2004 6	Semiconductor device structures whic	257/411 257/420,1		X			US 20040	
2		Hoshino,Ka	US 200200	2002 2	Magnetoresistive head, producing me	360/32 360/219,		X			US 20020	
3		Shinkawa,T	US 200200	2002 2	Semiconductor device and method of	257/74 257/421,5		X			US 20020	
4		Denkou,AI	US 6791125	2004 6	Semiconductor device structures whic	257/19 257/406		X			US 679112	
5		HOSHINO,KA	JP 2002197	2002 12	MAGNETO-RESISTANCE EFFECT HEAD,ITS			X			JP 200219	
6		UZUMAKI,TA	JP 0518621	1993 3	PRODUCTION OF SUPERCONDUCTOR THIN	505/A70		X			JP 051862	
7			JP 5903050	198405	Optical circuit baseplate - has substrat			X			JP 590305	